

IN THE ABSTRACT:

Please replace the Abstract of the Invention with the following rewritten

Abstract:

--The present invention relates to an active matrix type display providing a thin film transistor (TFT) as a switching device and which can obtain a large storage capacitor without thinning an insulating film between electrodes or expanding an electrode to a pixel area. The active matrix type display is structured to have a plurality of gate wirings formed on a glass substrate, a plurality of data wirings formed on the glass substrate substantially orthogonal to the gate wirings, the TFT decided by the gate wirings and data wirings and formed in a plurality of pixel areas arranged in a matrix shape, a pixel electrode formed inside the pixel area and connected to the TFT, and a plurality of storage capacitor electrodes layers formed a plurality of storage capacitors between the glass substrate and pixel electrode via a plurality of insulating films.--